### INTEGRATED CIRCUITS

## DATA SHEET

# **74LV14**Hex inverting Schmitt-trigger

Product specification Supersedes data of 1997 Feb 03 IC24 Data Handbook







**Philips Semiconductors Product specification** 

## Hex inverting Schmitt-trigger

74LV14

#### **FEATURES**

- Wide operating voltage: 1.0 to 5.5 V
- Optimized for Low Voltage applications: 1.0 to 3.6 V
- Accepts TTL input levels between V<sub>CC</sub> = 2.7 V and V<sub>CC</sub> = 3.6 V
- Typical V<sub>OLP</sub> (output ground bounce) < 0.8 V at V<sub>CC</sub> = 3.3 V,  $T_{amb} = 25^{\circ}C.$
- Typical V<sub>OHV</sub> (output V<sub>OH</sub> undershoot) > 2 V at V<sub>CC</sub> = 3.3 V,  $T_{amb} = 25^{\circ}C.$
- Output capability: standard
- I<sub>CC</sub> category: SSI

#### **APPLICATIONS**

• Wave and pulse shapers for highly noisy environments

#### **DESCRIPTION**

The 74LV14 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT14.

The 74LV14 provides six inverting buffers with Schmitt-trigger action. It is capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

#### QUICK REFERENCE DATA

GND = 0 V;  $T_{amb} = 25^{\circ}C$ ;  $t_r = t_f \le 2.5 \text{ ns}$ 

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay nA to nY	$C_L = 15 \text{ pF};$ $V_{CC} = 3.3 \text{ V}$	13	ns
C <sub>I</sub>	Input capacitance		3.5	pF
C <sub>PD</sub>	Power dissipation capacitance per gate	See Notes 1 and 2	15	pF

#### NOTES:

- C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W) P<sub>D</sub> = C<sub>PD</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>i</sub> +  $\sum$  (C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) where: f<sub>i</sub> = input frequency in MHz; C<sub>L</sub> = output load capacitance in pF; f<sub>o</sub> = output frequency in MHz; V<sub>CC</sub> = supply voltage in V;

  - $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$
- 2. The condition is  $V_I = GND$  to  $V_{CC}$ .

#### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
14-Pin Plastic DIL	-40°C to +125°C	74LV14 N	74LV14 N	SOT27-1
14-Pin Plastic SO	–40°C to +125°C	74LV14 D	74LV14 D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +125°C	74LV14 DB	74LV14 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV14 PW	74LV14PW DH	SOT402-1

#### PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 3, 5, 9, 11, 13	1A – 6A	Data inputs
2, 4, 6, 8, 10, 12	1Y – 6Y	Data outputs
7	GND	Ground (0 V)
14	V <sub>CC</sub>	Positive supply voltage

#### **FUNCTION TABLE**

INPUT	OUTPUT
nA	nY
L	Н
Н	L

#### NOTES:

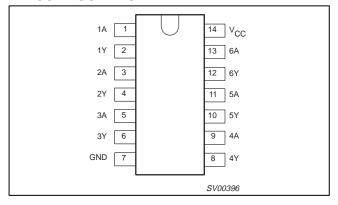
H = HIGH voltage level L = LOW voltage level

Philips Semiconductors Product specification

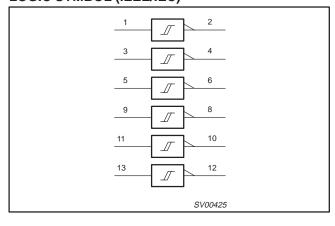
## Hex inverting Schmitt-trigger

74LV14

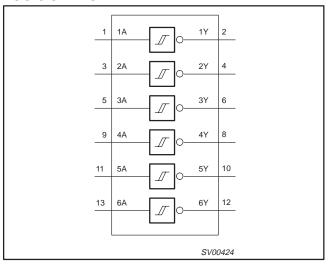
#### **PIN CONFIGURATION**



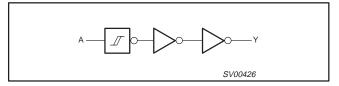
#### LOGIC SYMBOL (IEEE/IEC)



#### **LOGIC SYMBOL**



#### **LOGIC DIAGRAM**



#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>CC</sub>	DC supply voltage	See Note1	1.0	3.3	5.5	V
VI	Input voltage		0	-	V <sub>CC</sub>	V
Vo	Output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C

#### NOTE

1. The LV is guaranteed to function down to  $V_{CC}$  = 1.0V (input levels GND or  $V_{CC}$ ); DC characteristics are guaranteed from  $V_{CC}$  = 1.2V to  $V_{CC}$  = 5.5V.

3

1998 Apr 20

Downloaded from Elcodis.com electronic components distributor

74LV14

#### **ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
± I <sub>IK</sub>	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5V$	20	mA
± I <sub>OK</sub>	DC output diode current	$V_{O} < -0.5 \text{ or } V_{O} > V_{CC} + 0.5 V$	50	mA
±I <sub>O</sub>	DC output source or sink current  – standard outputs	$-0.5V < V_O < V_{CC} + 0.5V$	25	mA
±I <sub>GND</sub> , ±I <sub>CC</sub>	DC V <sub>CC</sub> or GND current for types with – standard outputs		50	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C
P <sub>TOT</sub>	Power dissipation per package  – plastic DIL  – plastic mini-pack (SO)  – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

#### NOTES:

#### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-4	0°C to +8∜	5°C	-40°C to	+125°C	UNIT
1			MIN	TYP <sup>1</sup>	MAX	MIN	MAX	1
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$		1.2				
	111011121	$V_{CC} = 2.0V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$	1.8	2.0		1.8		]
V <sub>OH</sub>	HIGH level output voltage; all outputs	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$	2.5	2.7		2.5		V
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$	2.8	3.0		2.8		]
		$V_{CC} = 4.5V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$	4.3	4.5		4.3		1
V <sub>OH</sub>	HIGH level output voltage;	$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $-I_O = 6mA$	2.40	2.82		2.20		
VOH	STANDARD outputs	$V_{CC} = 4.5V$ ; $V_I = V_{IH}$ or $V_{IL;} -I_O = 12mA$	3.60	4.20		3.50		
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0				
	LOW lovel output	$V_{CC} = 2.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2	]
V <sub>OL</sub>	LOW level output voltage; all outputs	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2	V
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2	]
		$V_{CC} = 4.5V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2	
VOL	LOW level output voltage;	$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 6mA$		0.25	0.40		0.50	
VOL	STANDARD outputs	$V_{CC} = 4.5V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 12mA$		0.35	0.55		0.65	]
I <sub>I</sub>	Input leakage current	$V_{CC} = 5.5V$ ; $V_I = V_{CC}$ or GND			1.0		1.0	μА
I <sub>CC</sub>	Quiescent supply current; SSI	$V_{CC} = 5.5V$ ; $V_I = V_{CC}$ or GND; $I_O = 0$			20.0		40	μА
Δl <sub>CC</sub>	Additional quiescent supply current	$V_{CC} = 2.7V$ to 3.6V; $V_{I} = V_{CC} - 0.6V$			500		850	μА

#### NOTE:

<sup>1.</sup> Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>2.</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>1.</sup> All typical values are measured at  $T_{amb} = 25$ °C.

74LV14

#### TRANSFER CHARACTERISTICS

Voltages are referenced to GND (ground = 0 V)

				T <sub>amb</sub> (°C)				Т	EST CONDITIONS
SYMBOL	PARAMETER		–40 TO +85		–40 TC	+125	UNIT	V <sub>CC</sub>	WAVEFORMS
		MIN.	TYP.	MAX.	MIN.	MIN.		V <sub>CC</sub> (V)	WAVEFORWIS
		_	0.70	_	-	_		1.2	
		0.8	1.10	1.4	0.8	1.4		2.0	
$V_{T+}$		1.0	1.45	2.0	1.0	2.0		2.7	
	Positive-going threshold	1.2	1.60	2.2	1.2	2.2	V	3.0	Figure 1 and 2
	il il estiblic	1.5	1.95	2.4	1.5	2.4		3.6	
		1.7	2.50	3.15	1.7	3.15		4.5	
		2.1	3.00	3.85	2.1	3.85		5.5	
		_	0.34	_	_	_		1.2	
	Negative-going threshold	0.3	0.65	0.9	0.3	0.9		2.0	
		0.4	0.90	1.4	0.4	1.4	V	2.7	
$V_{T-}$		0.6	1.05	1.5	0.6	1.5		3.0	Figure 1 and 2
		0.8	1.30	1.8	0.8	1.8		3.6	
		0.9	1.60	2.0	0.9	2.0		4.5	
		1.1	2.00	2.6	1.1	2.6		5.5	
		_	0.30	_	_	_		1.2	
		0.2	0.55	0.8	0.2	0.8		2.0	
		0.3	0.60	1.1	0.3	1.1		2.7	
$V_{H}$	Hysteresis (V <sub>T+</sub> – V <sub>T-</sub> )	0.4	0.65	1.2	0.4	1.2	V	3.0	Figure 1 and 2
	(-17 -1-)	0.4	0.70	1.2	0.4	1.2		3.6	
		0.4	0.80	1.4	0.4	1.4		4.5	
		0.6	1.00	1.5	0.6	1.5		5.5	

- All typical values are measured at T<sub>amb</sub> = 25°C
   The V<sub>IH</sub> and V<sub>IL</sub> from the DC family characteristics are superseded by the V<sub>T+</sub> and V<sub>T-</sub>.

#### **AC CHARACTERISTICS**

GND = 0V;  $t_{\Gamma} \le t_f$  = 2.5ns;  $C_L$  = 50pF;  $R_L$  = 1K $\Omega$ 

			CONDITION			LIMITS			
SYMBOL	PARAMETER	WAVEFORM	CONDITION	-	40 to +85 °	С	-40 to -	<b>-125</b> °C	UNIT
			V <sub>CC</sub> (V)	MIN	TYP <sup>1</sup>	MAX	MIN	MAX	
	Propagation delay nA to nY		1.2		80				
			2.0		27	37		48	
t <sub>PHL/PLH</sub>			2.7		20	28		35	ns
			3.0 to 3.6		15 <sup>2</sup>	22		28	
			4.5 to 5.5			18		23	

5

#### NOTES:

- 1. Unless otherwise stated, all typical values are measured at  $T_{amb}$  = 25°C 2. Typical values are measured at  $V_{CC}$  = 3.3 V.

74LV14

#### TRANSFER CHARACTERISTIC WAVEFORMS

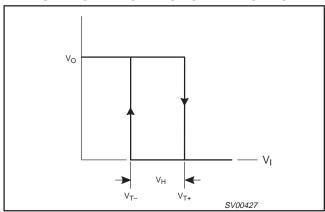


Figure 1. Transfer characteristic.

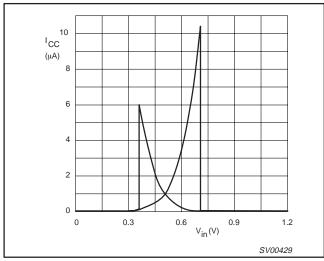


Figure 3. Typical 74LV14 transfer characteristics;  $V_{CC} = 1.2V$ .

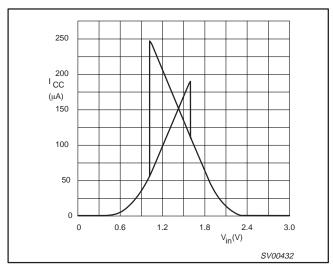
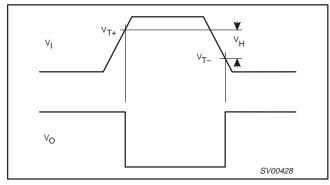


Figure 5. Typical 74LV14 transfer characteristics;  $V_{CC} = 3.0V$ .



 $\label{eq:total_problem} Figure 2. \ \ Definition of \ v_{T+}, \\ V_{T-} \ and \ V_{H+}; \\ where \ V_{T+} \ and \ V_{T-} \ are \ between \ limits \ of 20\% \ and \ 70\%$ 

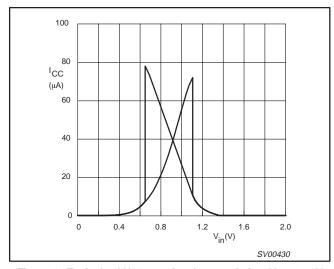


Figure 4. Typical 74LV14 transfer characteristics;  $V_{CC} = 2.0V$ .

#### **AC WAVEFORMS**

6

 $V_{M} = 1.5 \text{ V at } V_{CC} \ge 2.7 \text{ V};$ 

 $V_{M} = 0.5 \times V_{CC}$  at  $V_{CC} < 2.7 \text{ V}$ 

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are the typical output voltage drop that occur with the output load.

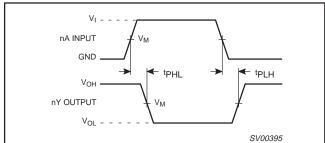


Figure 6. Input (nA) to output (nY) propagation delays.

#### **APPLICATION INFORMATION**

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

$$\mathsf{P}_{\mathsf{ad}} \quad = \mathsf{f}_{\mathsf{i}} \times (\mathsf{t}_{\mathsf{r}} \times \mathsf{I}_{\mathsf{CCa}} + \mathsf{t}_{\mathsf{f}} \times \mathsf{I}_{\mathsf{CCa}}) \times \mathsf{V}_{\mathsf{CC}}.$$

#### Where:

 $P_{ad}$  = additional power dissipation ( $\mu W$ )

f<sub>i</sub> = input frequency (MHz)

 $t_r$  = input rise time (ns); 10% – 90%  $t_f$  = input fall time (ns); 10% – 90%

 $I_{CCa}$  = average additional supply current ( $\mu$ A)

Average  $I_{CC_a}$  differs with positive or negative input transitions, as shown in Figure 7.

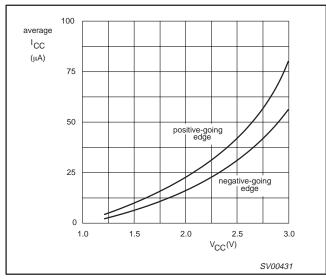


Figure 7. Average I $_{\rm CC}$  for LV Schmitt-trigger devices; linear change of V $_{\rm I}$  between 0.1 V $_{\rm CC}$  to 0.9 V $_{\rm CC}$ .

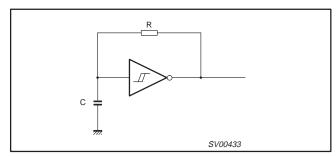


Figure 8. Relaxation oscillator using the LV14.

#### Note to application information:

All values given are typical unless otherwise specified.

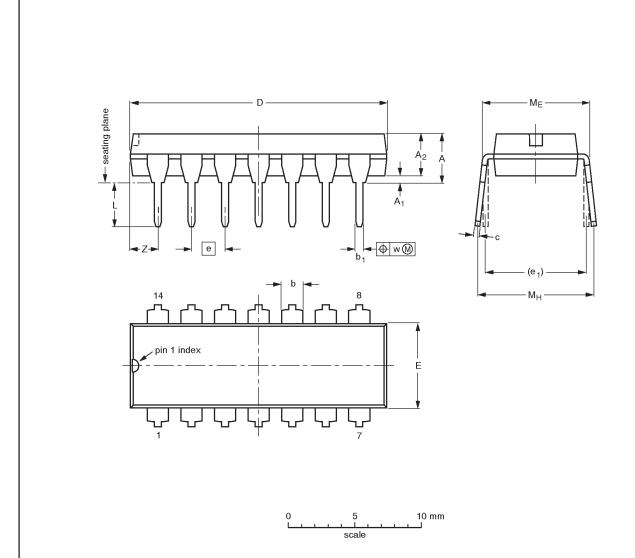
Note to Figure 8

$$f = \frac{1}{T} \approx \frac{1}{0.8 \, \times \, RC}$$

74LV14

#### DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



#### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	Мн	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

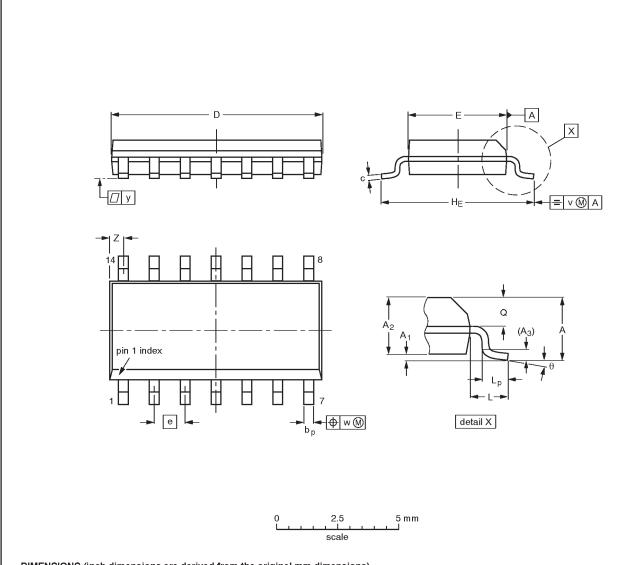
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT27-1	050G04	MO-001AA				<del>92-11-17</del> 95-03-11

1998 Apr 20 8

74LV14

#### SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



#### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	1 // //60	0.0098 0.0039		0.01		0.0098 0.0075	0.35 0.34	0.16 0.15	0.050	0.24 0.23	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

#### Note

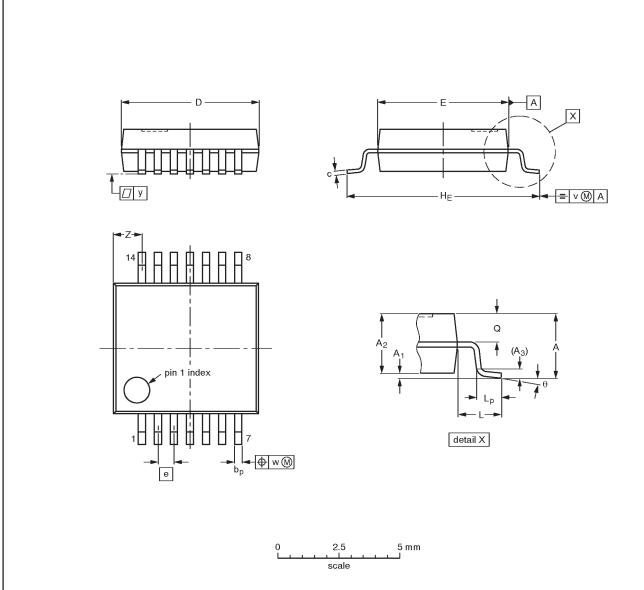
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT108-1	076E06\$	MS-012AB			<del>91-08-13</del> 95-01-23	

74LV14

## SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Ø	٧	w	у	Z <sup>(1)</sup>	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

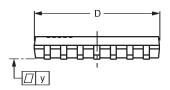
OUTLINE		REFER	RENCES		EUROPEAN ISSUE DAT				
VERSION	IEC	JEDEC	PROJECTION	1330E DATE					
SOT337-1		MO-150AB				<del>95-02-04</del> 96-01-18			

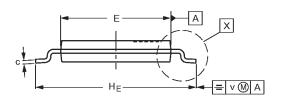
1998 Apr 20 10

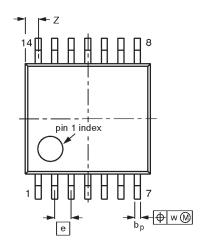
74LV14

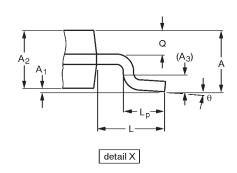
TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

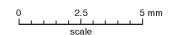
SOT402-1











#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	bр	c	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1990E DATE		
SOT402-1		MO-153			<del>-94-07-12</del> 95-04-04		

1998 Apr 20 1

74LV14

DEFINITIONS						
Data Sheet Identification	Product Status	Definition				
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.				
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.				
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.				

Philips Semiconductors and Philips Electronics North America Corporation reserve the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified. Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

#### LIFE SUPPORT APPLICATIONS

Philips Semiconductors and Philips Electronics North America Corporation Products are not designed for use in life support appliances, devices, or systems where malfunction of a Philips Semiconductors and Philips Electronics North America Corporation Product can reasonably be expected to result in a personal injury. Philips Semiconductors and Philips Electronics North America Corporation customers using or selling Philips Semiconductors and Philips Electronics North America Corporation Products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors and Philips Electronics North America Corporation for any damages resulting from such improper use or sale.

Philips Semiconductors 811 East Arques Avenue P.O. Box 3409 Sunnyvale, California 94088–3409 Telephone 800-234-7381 © Copyright Philips Electronics North America Corporation 1998 All rights reserved. Printed in U.S.A.

print code Date of release: 05-96

Document order number: 9397-750-04409

Let's make things better.

Philips Semiconductors



